NSN 5962-01-444-3950

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and electrostatic sensitive and low power
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
110.00 milliamperes supply
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, memory, digital, cmos, 128k x 8 static random access memory (sram) low power, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Time Rating Per Chacteristic:
70.00 nanoseconds access
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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